

FDD6N50F / FDU6N50F N-Channel MOSFET 500V, 5.5A, 1.15Ω

Features

- $R_{DS(on)} = 0.95\Omega$ (Typ.)@ $V_{GS} = 10V$, $I_D = 2.75A$
- Low gate charge (Typ. 15nC)
- Low C_{rss} (Typ. 6.3pF)
- · Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- · RoHS compliant



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Description

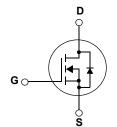
These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advance technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficient switched mode power supplies and active power factor correction.

January 2012 UniFET[™]







MOSFET Maximum Ratings T_C = 25°C unless otherwise noted*

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain to Source Voltage			500	V
V _{GSS}	Gate to Source Voltage			±30	V
I _D DrainCurrent	Drain Current	-Continuous (T _C = 25 ^o C)		5.5	Α
	DrainCurrent	-Continuous (T _C = 100 ^o C)		2.4	
I _{DM}	Drain Current	- Pulsed	(Note 1)	22	А
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	270	mJ
I _{AR}	Avalanche Current		(Note 1)	5.5	A
E _{AR}	Repetitive Avalanche Energy		(Note 1)	8.9	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	20	V/ns
P _D	Dever Dissignation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		89	W
	Power Dissipation	- Derate above 25°C		0.71	W/ ^o C
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C

Thermal Characteristics

Symbol	Parameter	Ratings	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.4	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	83	0/00

*When mounted on the minimum pad size recommended (PCB Mount)

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	mm mm - - 500 - - - - - - - - - - - - - - -	Typ. - 0.15 - - 0.95 4.3	2500 2000 70 Max. - - 10 100 ±100 ±100	Units V V/°C μΑ nA V Ω S
2°C	- Min. 500 3.0 -	- 0.15 - - - 0.95	70 Max. - 10 100 ±100	V V/°C μΑ nA V
2°	500 - - - 3.0 - -	- 0.15 - - - 0.95	Max. - - 10 100 ±100	V V/°C μΑ nA V
2°	500 - - - 3.0 - -	- 0.15 - - - 0.95	- - 10 100 ±100	V V/°C μΑ nA V
2°	500 - - - 3.0 - -	- 0.15 - - - 0.95	- - 10 100 ±100	V V/°C μΑ nA V
2°	500 - - - 3.0 - -	- 0.15 - - - 0.95	- - 10 100 ±100	V V/°C μΑ nA V
2°	- - - 3.0 -	0.15 - - - - 0.95	- 10 100 ±100	V/°C - μΑ nA V Ω
2°	- - - 3.0 -	0.15 - - - - 0.95	- 10 100 ±100	V/°C - μΑ nA V Ω
	- - 3.0 - -	- - - 0.95	10 100 ±100	- μA nA V Ω
(Note 4)	- - 3.0 - -	0.95	100 ±100	nA V Ω
(Note 4)	3.0 - -	0.95	±100	nA V Ω
(Note 4)	3.0 - -	0.95	5.0	V Ω
(Note 4)	-	0.95	-	Ω
(Note 4)	-	0.95	-	Ω
(Note 4)	-		1.15 -	
(Note 4)	-	4.3	-	S
	-			
	-			
_		720	960	pF
	-	85	115	pF
	-	6.3	9.5	pF
	-	15	19.8	nC
	-	4.4	-	nC
ote 4, 5)	-	6.1	-	nC
0.0 1, 0)				
	-	17	44	ns
	-	28.3	66.6	ns
	-	33.4	76.7	ns
ote 4, 5)	-		51	ns
,				
	-	-	5.5	A
	-	-		A
	-	-	1.5	V
	-		-	ns
(Note 4)	_		-	μC
	(Note 4)	- - - -	 - 85	5.5 22 1.5 - 85 -

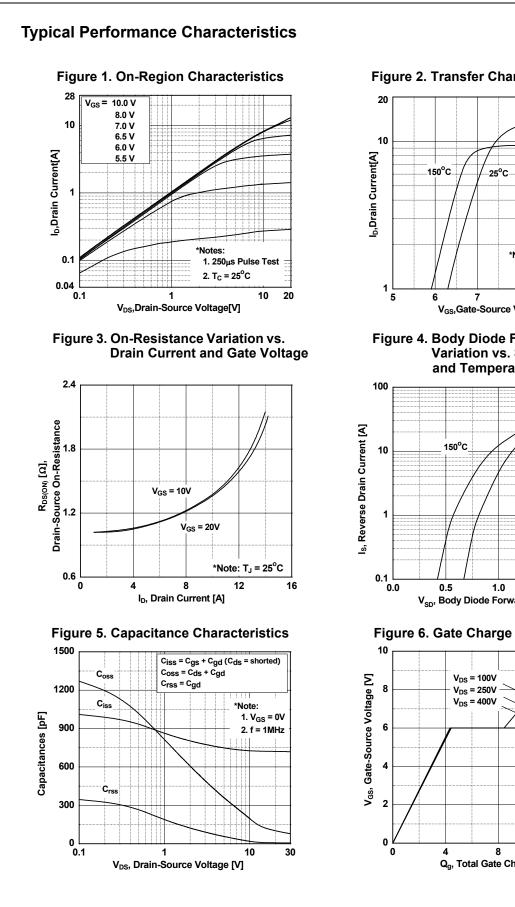
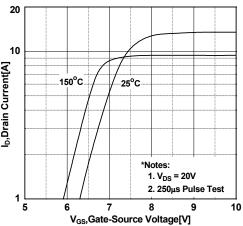
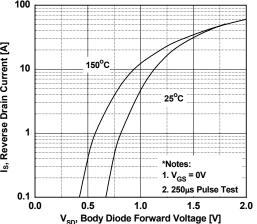


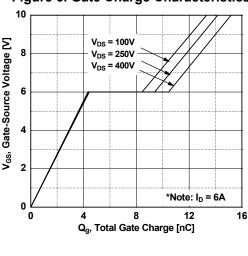
Figure 2. Transfer Characteristics

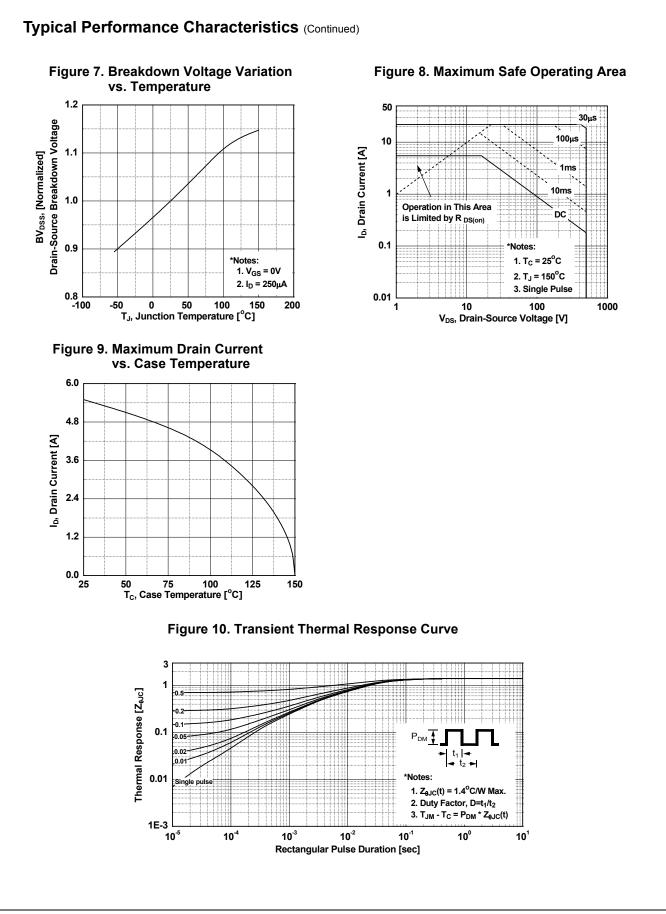






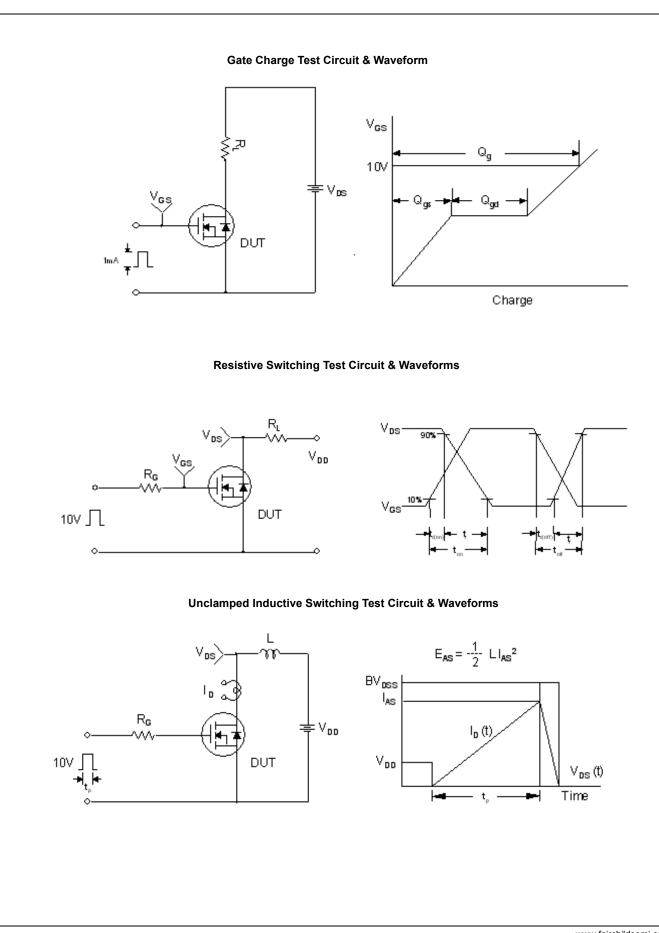






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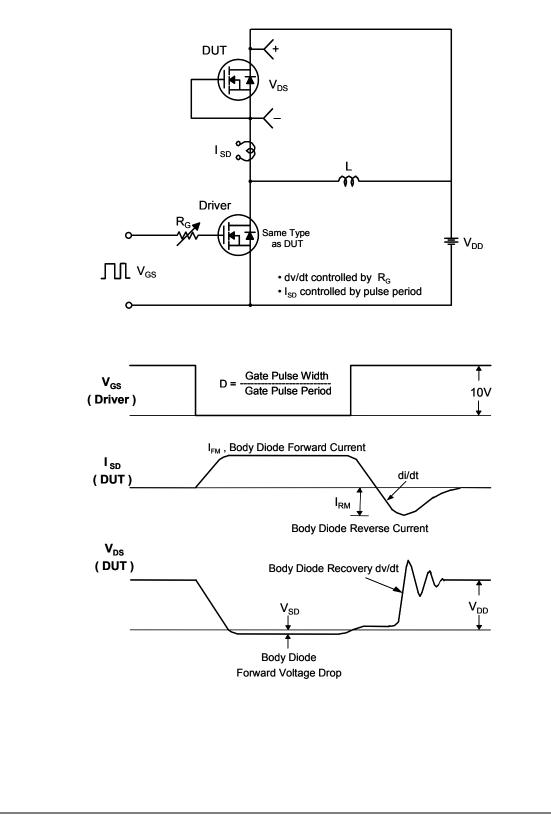




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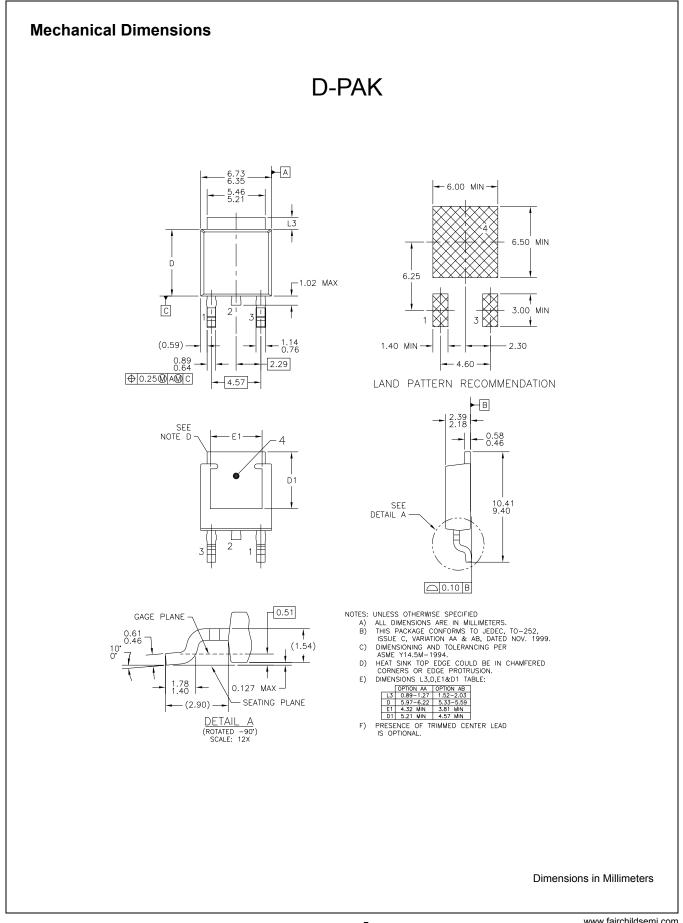
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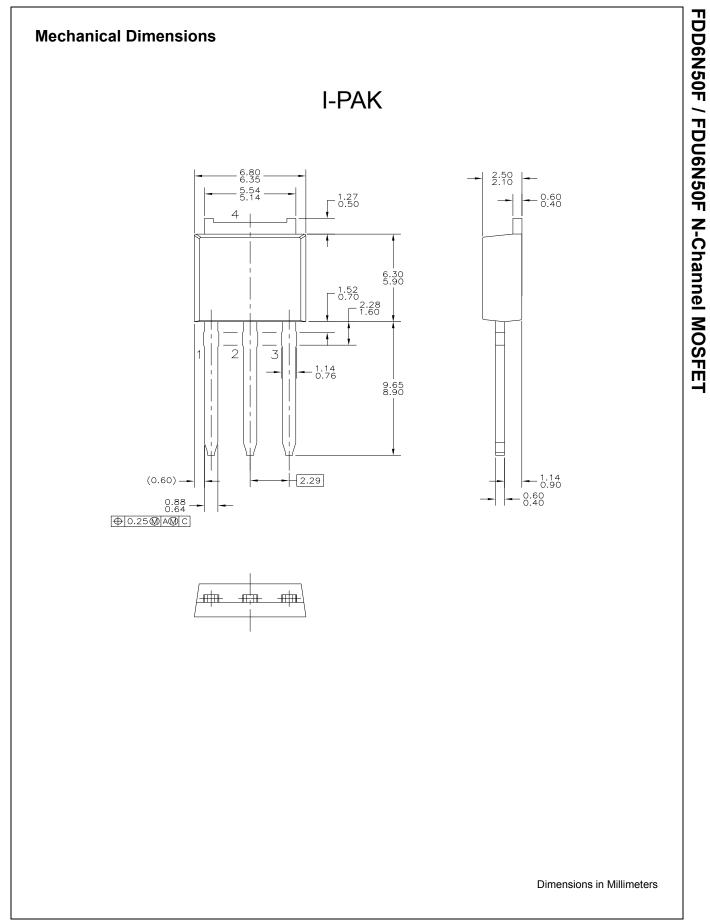
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